COMPLIANT

HALOGEN FREE



Vishay Semiconductors

## Ultralow V<sub>F</sub> Hyperfast Rectifier for Discontinuous Mode PFC, 8 A FRED Pt<sup>®</sup>



2L TO-220 FullPAK



VS-8ETL06FP-N3

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	8 A			
V <sub>R</sub>	600 V			
V <sub>F</sub> at I <sub>F</sub>	0.81 V			
t <sub>rr</sub> typ.	60 ns			
T <sub>J</sub> max.	175 °C			
Package	2L TO-220 FullPAK			
Circuit configuration	Single			

#### **FEATURES**

- · Hyperfast recovery time
- Benchmark ultralow forward voltage drop
- 175 °C operating junction temperature
- · Low leakage current
- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- UL pending
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **DESCRIPTION**

State of the art, ultralow  $V_F$ , soft-switching hyperfast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

#### **APPLICATIONS**

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Repetitive peak reverse voltage	$V_{RRM}$		600	V
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 142 °C	8	Α
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	175	
Repetitive peak forward current	I <sub>FM</sub>		16	
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-	
Forward voltage V <sub>F</sub>	I <sub>F</sub> = 8 A	-	0.96	1.05	V	
	I <sub>F</sub> = 8 A, T <sub>J</sub> = 150 °C	-	0.81	0.86		
Reverse leakage current I <sub>R</sub>		$V_R = V_R$ rated	-	0.05	5	μA
neverse leakage current	I <sub>R</sub>	T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	20	100	μΑ
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	17	-	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body - 8.0 -		nΗ		



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	60	100	
Reverse recovery time t <sub>rr</sub>	+	$I_F = 8 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	150	250	ns
	T <sub>J</sub> = 25 °C		-	170	-		
	T <sub>J</sub> = 125 °C		-	250	-		
Peak recovery current I <sub>RRM</sub>	1	T <sub>J</sub> = 25 °C	$I_F = 8 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 390 \text{ V}$	-	15	-	Α
	IRRM	T <sub>J</sub> = 125 °C		-	20	-	^
Reverse recovery charge Q <sub>rr</sub>	0	T <sub>J</sub> = 25 °C		-	1.3	-	μC
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	2.6	-	μΟ

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C
Thermal resistance, junction-to-case	R <sub>thJC</sub>		i	3.4	4.3	°C/W
Thermal resistance, junction-to-ambient per leg	R <sub>thJA</sub>	Typical socket mount	i	-	70	
Thermal resistance, case-to-heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.5	-	
Weight			1	2.0	-	g
weignt			-	0.07	-	OZ.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style 2L TO-220 FullPAK	8ETL06FP			

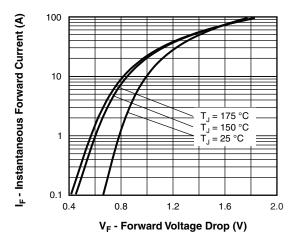


Fig. 1 - Typical Forward Voltage Drop Characteristics

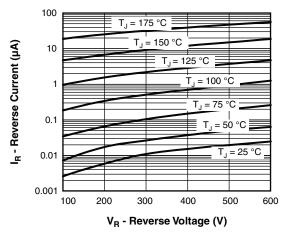


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



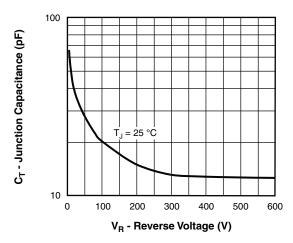


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

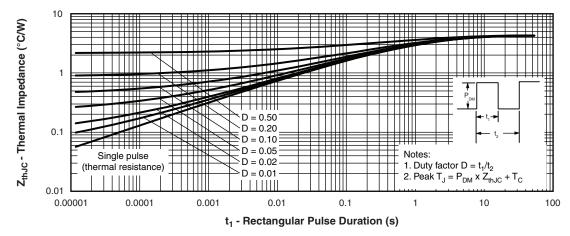


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

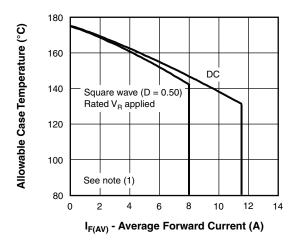


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

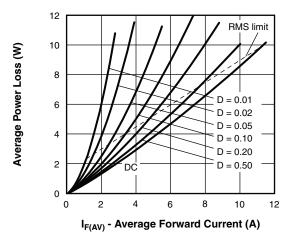


Fig. 6 - Forward Power Loss Characteristics

#### Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 5)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D)}; I_R \text{ at } V_{R1} = \text{rated } V_R \\ \end{array}$ 



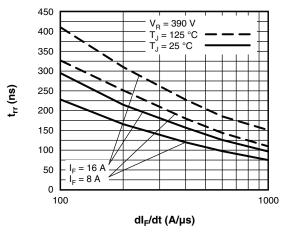


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

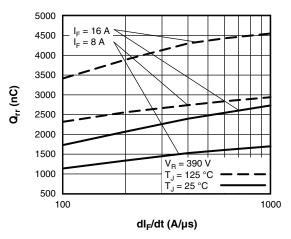
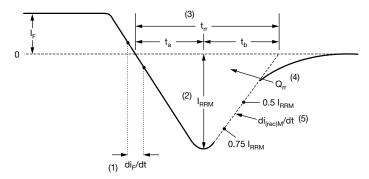


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt



- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3) t<sub>rr</sub> reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75 I<sub>RRM</sub> and 0.50 I<sub>RRM</sub> extrapolated to zero current.
- (4)  $\mathbf{Q}_{rr}$  area under curve defined by  $\mathbf{t}_{rr}$  and  $\mathbf{I}_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

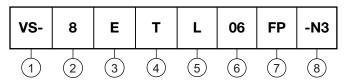
(5)  $di_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 9 - Reverse Recovery Waveform and Definitions



### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

2 - Current rating (8 = 8 A)

**3** - E = single

- T = TO-220, D<sup>2</sup>PAK (TO-263AB)

L = ultralow V<sub>F</sub> hyperfast recovery

6 - Voltage rating (06 = 600 V)

7 - FP = 2L TO-220 FullPAK

8 - Environmental digit:

-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

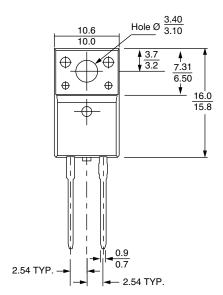
ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-8ETL06FP-N3	50	1000	Antistatic plastic tube		

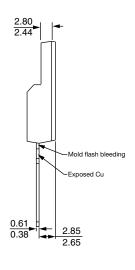
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?96157</u>				
Part marking information	www.vishay.com/doc?95392			
SPICE model	www.vishay.com/doc?96054			

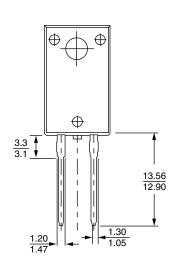


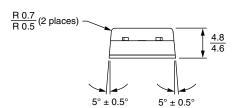
### 2L TO-220 FullPAK

#### **DIMENSIONS** in millimeters









Bottom view



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Vishay

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